UNITED STATES SECURITIES AND EXCHANGE COMMISSION

Washington, D.C. 20549

FORM 8-K

CURRENT REPORT

Pursuant to Section 13 or 15(d) of the Securities Exchange Act of 1934

May 14, 2013 **Date of Report (Date of earliest event reported)**

DIODES INCORPORATED

(Exact name of registrant as specified in its charter)

Delaware	002-25577	95-203951	
(State or other jurisdiction	(Commission	(I.R.S. Employe	
of incorporation)	File Number)	Identification N	

(972) 987-3900 (Registrant's telephone number, including area code)

4949 Hedgcoxe Road, Suite 200 Plano, Texas

(Address of principal executive offices)

75024

(Zip Code)

k the appropriate box below if the Form 8-K filing is intended to simultaneously satisfy the filing obligation of the registrant under any of the following isions:
Written communications pursuant to Rule 425 under the Securities Act (17 CFR 230.425)
Soliciting material pursuant to Rule 14a-12 under the Exchange Act (17 CFR 240.14a-12)
Pre-commencement communications pursuant to Rule 14d-2(b) under the Exchange Act (17 CFR 240.14d-2(b))
Pre-commencement communications pursuant to Rule 13e-4(c) under the Exchange Act (17 CFR 240.13e-4(c))

Item 7.01. Regulation FD Disclosure.

On May 14, 2013, the Company representatives attended J.P. Morgan 41st Annual Global Technology, Media and Telecom Conference in Boston, Massachusetts and held a presentation meeting. A copy of the presentation slides is attached as Exhibit 99.1 to this Report.

The information in this Item 7.01, including Exhibit 99.1, will not be treated as filed for the purposes of Section 18 of the Securities Exchange Act of 1934 (the "Exchange Act") or otherwise subject to the liabilities of that section. This information will not be incorporated by reference into a filing under the Securities Act of 1933, or into another filing under the Exchange Act, unless that filing expressly refers to specific information in this Report. The furnishing of the information in this Item 7.01 is not intended to, and does not, constitute a representation that such furnishing is required by Regulation FD or that the information in this Item 7.01 is material information that is not otherwise publicly available.

In the presentation, the Company utilized financial measures and terms not calculated in accordance with generally accepted accounting principles in the United States ("GAAP") in order to provide stockholders with an alternative method for assessing our operating results in a manner that enables stockholders to more thoroughly evaluate our current performance as compared to past performance. We also believe these non-GAAP measures provide stockholders with a more informed baseline for modeling the Company's future financial performance. Our management uses these non-GAAP measures for the same purpose. We believe that our stockholders should have access to, and that we are obligated to provide, the same set of tools that we use in analyzing our results. These non-GAAP measures should be considered in addition to results prepared in accordance with GAAP, but should not be considered a substitute for or superior to GAAP results. See Exhibit 99.1 to the Company's Form 8-K, filed on May 14, 2013 for definitions of the non-GAAP financial measures, together with an explanation of why management uses these measures and why management believes that these non-GAAP financial measures are useful to stockholders. In addition, in Exhibit 99.1 to the Company's Form 8-K, filed on May 14, 2013, we have provided tables to reconcile the non-GAAP financial measures utilized to GAAP financial measures.

Cautionary Information Regarding Forward-Looking Statements

Except for the historical and factual information contained in the press release attached as Exhibit 99.1, the matters set forth in the press release (including statements as to the expected benefits of the acquisition and other statements identified by words such as "estimates," "expects," "projects," "plans," "will" and similar expressions) are forward-looking statements within the meaning of the "safe harbor" provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements are subject to risks and uncertainties that may cause actual results to differ materially, including: the risk that BCD's business will not be integrated successfully into the Company's; the risk that the expected benefits of the acquisition may not be realized; the risk that BCD's standards, procedures and controls will not be brought into conformance within the Company's operations; difficulties coordinating the Company's and BCD's new product and process development, hiring additional management and other critical personnel, and increasing the scope, geographic diversity and complexity of the Company's operations; difficulties in consolidating facilities and transferring processes and know-how; difficulties in reducing the costs of BCD's business; the diversion of our management's attention from the management of our business; the risk that we may not be able to maintain our current growth strategy or continue to maintain our current performance, costs and loadings in our manufacturing facilities; risks of domestic and foreign operations, including excessive operating costs, labor shortages, higher tax rates and our joint venture prospects; the risk of unfavorable currency exchange rates; our future guidance may be incorrect; the global economic weakness may be more severe or last longer than we currently anticipated; and the impact of competition and other risk factors relating to our industry and business as detailed from time to time in the Company's reports filed with the SEC. You should not place

Item 9.01. Financial Statements and Exhibits.

(d) Exhibits

Exhibit
Number

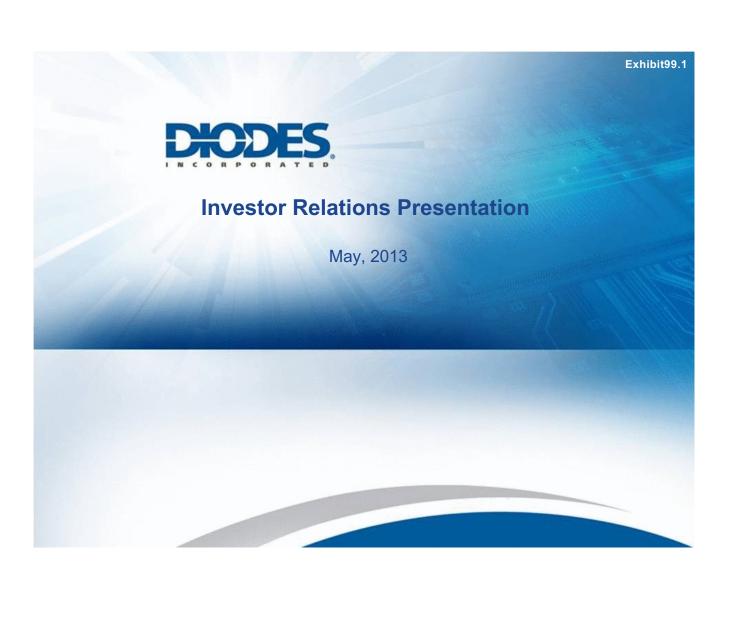
99.1 Presentation Slides for J.P. Morgan 41st Annual Global Technology, Media and Telecom Conference in Boston, Massachusetts on May 14, 2013

SIGNATURES

Pursuant to the requirements of the Securities Exchange Act of 1934, the Registrant has duly caused this report to be signed on its behalf by the undersigned hereunto duly authorized.

Dated: May 21, 2013 DIODES INCORPORATED

By /s/ Richard D. White
RICHARD D. WHITE
Chief Financial Officer



Safe Harbor Statement

Any statements set forth herein that are not historical facts are forward-looking statements that involve risks and uncertainties that could cause actual results to differ materially from those in the forward-looking statements. Such forward-looking statements include, but are not limited to, statements regarding Diodes Incorporated's 2Q 2013 business outlook update, which includes the following: a summary of the guidance for GAAP and non-GAAP financial measures as follows on revenue of \$206 million to \$218 million for both GAAP and non-GAAP; sequential growth of 16% to 23% for both GAAP and non-GAAP; gross margir(% of revenue) of 25.0% to 29.0% for GAAP and 27.0% to 31.0% for non-GAAP; operating expense (% of revenue) of 22.6% to 24.6% for GAAP and 20.3% to 22.3% for non-GAAP; tax rate of 14% to 20% for both GAAP and non-GAAP; and shares used to calculate GAAP and non-GAAP are anticipated to be approximately47.4 millionand other statements identified by words such as "estimates," "expects," "projects," "plans," "will" and similar expressions.

Potential risks and uncertainties include, but are not limited to, such factors as: the possibility that the transaction may not be consummated, including as a result of any of the conditions precedent; the risk that BCD's business will not be integrated successfully into the Company's; the risk that the expected benefits of the acquisition may not be realized, including the realization of the accretive effect of the acquisition; the risk that BCD's standards, procedures and controls will not be brought into conformance within the Company's operation; difficulties coordinating the Company's and BCD's new product and process development, hiring additional management and other critical personnel, and increasing the scope, geographic diversity and complexity of the Company's operations; difficulties in consolidating facilities and transferring processes and know-how; difficulties in reducing the costs of BCD's business; the diversion of our management's attention from the management our business; Diodes' business and growth strategy; the introduction and market reception to new product announcements; fluctuations in product demand and supply; prospects for the global economy; continued introduction of new products; Diodes' ability to maintain customer and vendor relationships; technological advancements; impact of competitive products and pricing; growth in targeted markets; successful integrations acquired companies and/orassets; Diodes' ability of successfully make additional acquisitions; risks of domestic and foreign operations, including excessive operation costs, labor shortages, higher tax rates and joint venture prospects; unfavorable currency exchange rates; availability tax credits; Diodes' ability maintainits current growth strategy or continue to maintain its current performance and loadings in manufacturing facilities; our future guidance may be incorrect; the global economic weakness may be more severe or last longer than Diodes currently anticipate; and other information detailed from time to time i

This presentation also contains non-GAAP measures. See the Company's press releases on May 9, 2013 titled, "Diodes Incorporated Reports First Quarter 2013 Financial Results" for detailed information related to the Company's non-GAAP measures and a reconciliation of GAAP net income (loss) to non-GAAP net income (loss).



Management Representative



Rick White CFO, Secretary, and Treasurer

CFO Since 2009
SR VP, Finance 3 years
Texas Instruments 25 years

Experience:

- Partner, Tatum Partners
- CFO, Optisoft
- Vice President, TI Worldwide, Memory

Education:

- MBA, Finance, University of Michigan
- Bachelor's Degree, Electrical Engineering, Oklahoma State University



Company Representative

Laura Mehrl

Director of Investor Relations

Since May 2010

Experience:

- Director of Investor Relations, Diodes Incorporated, Plano, Texas
- Senior Business Development Manager, STMicroelectronics, Carrollton, Texas
- Sales Director for Analog Devices Inc., Shanghai, China
- Product Marketing Manager at Texas Instruments (TI), Dallas, Texas
- Senior Engineer at Lattice Semiconductor Inc., Hillsboro, Oregon
- Wafer fab design engineer and product engineer at TI, Lubbock, Texas

Education:

- MBA with concentration in International Marketing, Texas Tech University
- BS in Electrical and Computer Engineering, University of Iowa



About Diodes Incorporated

A leading global manufacturer and supplier of high-quality application specific, standard products within the broad discrete, logic and analog markets, serving the computing, consumer, industrial, communications and automotive segments.





Business Objective

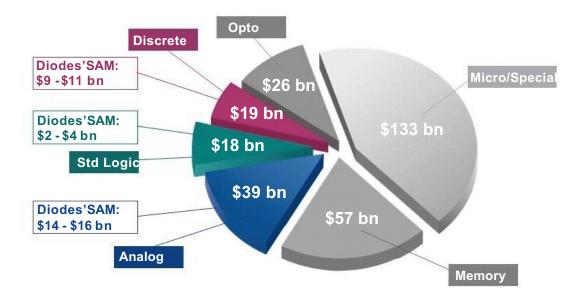
To consistently achieve above-market profitable growth, utilizing our innovative and cost-effective packaging technology, suited for high volume, high growth markets by leveraging process expertise and design excellence to deliver high quality semiconductor products.





Significant Market Opportunity

2012 Total Semiconductor Market (\$292 bn)





Diodes Growth Strategy

Many Paths for Growth:

Product Portfolio

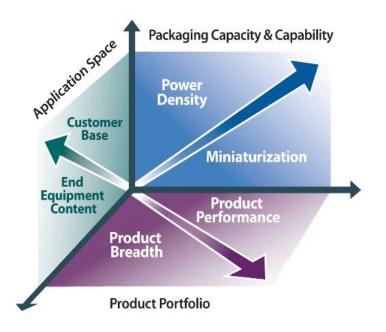
- Product arena
- Product line expansion
- Performance enhancement

Application Space

- Targeted end equipment
- Broad customer base
- Increased product coverage

Packaging Breadth

- Broad packaging portfolio
- Increased power density
- Small form factor





Product Portfolio Progression

Discrete

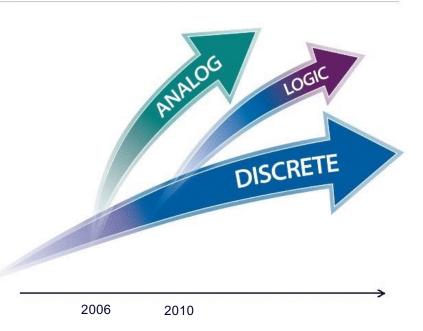
- Diodes
- MOSFETs
- Rectifiers
- Transistors
- Protection Devices

Analog

- Power Management
- Power Switches
- Standard Linear
- Sensors
- LED Drivers

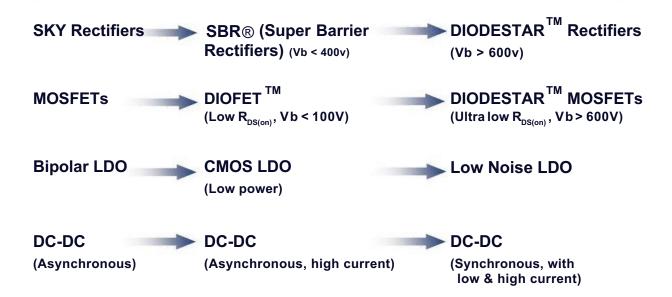
Logic

- Low Voltage CMOS
- High Speed CMOS
- Advanced Ultra-Low Power CMOS





Performance Enhancement



Diodes' product upgrade has expanded our SAM.



Efficiency, Functionality and Control for Smartphones

LCD Backlighting

LED Drivers Boost Converters Schottky Diodes

LED Flash Module

Camera Flash Drivers ZXMN series MOSFETs

LCD / OLED Display Bias

LCD Bias ICs OLED Bias ICs Schottky Diodes

■ Battery Power Management

USB Power Switches
Current Monitors
Charger ICs
Low-Saturation Bipolar Transistors
ZXMP series MOSFETs



GPS Antenna Detection

Current Monitors

■ RF Power Amplifier

Low Dropout Regulators

System Voltage Conversion

Low Dropout Regulators DC-DC Converters Schottky Diodes Low-Saturation Bipolar Transistors

Flip / Slide / Holstor Detection

Hall Effect Sensors Hall Effect Drivers

Keypad Backlighting

LED Drivers Boost Converters Schottky Diodes

Audio Amplifier

Class D Amplifier



Strong Relationships Drive LCD/LED TV Product Roadmaps

LCD Display Buffer

40V High-gain BJT

■ System Power Conversion

Low Dropout Regulators
DC-DC Converters
Voltage References
Synchronous MOSFET Controllers
40V/100V SBR and Schottkys
Bridge Rectifier Diodes

LCD LED Backlighting

Current Monitors 400V High-gain NPN BJT 60V/100V High-gain NPN BJT 60V/100V N-channel MOSFETS

CCFL Backlighting

30V Low On-resistance MOSFETs



DC-DC Converters 40V Schottkys

System Interface

USB Power Switches Zener and TVS Arrays

System Power Management

Buck DC-DC Converters
Low Dropout Regulators
20V/30V/40V SBR® and Schottkys
30V P-Channel MOSFETs
30V Low-saturation PNP BJT

Audio Amplifier

Buck DC-DC Converters Schottky Diodes SBR Class D Amplifier



Product Breadth and Performance for Computing Platforms

LCD / LED Backlighting

LED Drivers Boost Converters Schottky Diodes

System Voltage Conversion

Low Dropout Regulators DC-DC Converters Schottky Diodes Low-Saturation BJT

Battery Power Management

Current Monitors Load Switches Low-Saturation BJT ZXMP series MOSFETs

Open / Close Detection

Hall Effect Sensors Hall Effect Drivers



Buck DC-DC Converters Schottky Diodes Super Barrier Rectifiers Class D Amplifier

Wireless Connectivity

DC-DC Converters Low Dropout Regulators

System Power Management

Buck DC-DC Converters Low Dropout Regulators Super Barrier Rectifiers Schottky Diodes P-Channel MOSFETs Low-Saturation BJT

System Interface

USB Power Switches Zener and TVS Arrays



Packaging Focus: Miniaturization and Power Efficiency

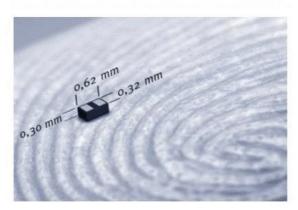




Packaging Focus: Miniaturization and Power Efficiency

Miniaturization

DFN 0603-2 Possibly the smallest Discrete semiconductor package.



Power Efficiency

Compared to a TO252, the PowerDI®5 package delivers twice the power density from





Efficient Manufacturing + Superior Processes

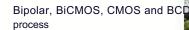
Packaging

- Shanghai-based packaging with capacity approximately 30 billion units
- Flexible and optimized manufacturing process = low packaging cost
- Additional packaging facilities in Neuhaus Germany and joint venture in Chengdu, China



Wafer Fabs

Two discrete fabs, two analog fabs in Kansas City, Missouri (5"and 6"), Oldham, United Kingdom (6"), and Shanghai (6") respectively



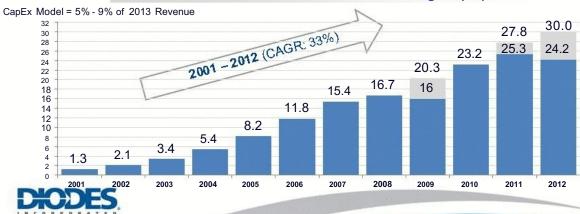






Strong engineering capabilities

Economies of Scale: Production Units in Shanghai (bn)



Collaborative Customer Relationships



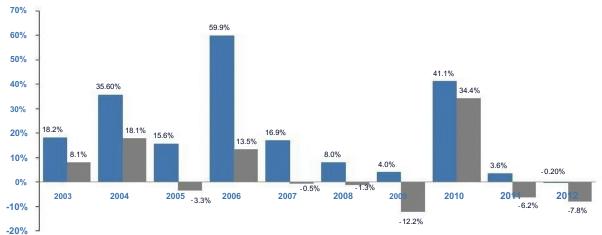


Outperforming the Industry

Annual Revenue Growth Rates

2003 to 2012 Growth

Diodes Inc.: 19% SAM Industry: 4.3%

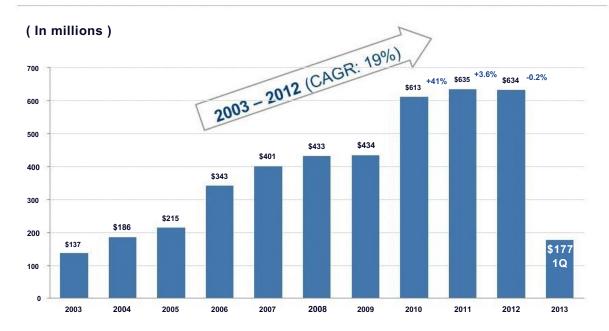




Industry (Discrete + Analog + Logic)

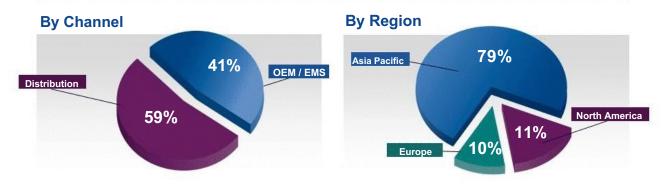
*Acquisition Years

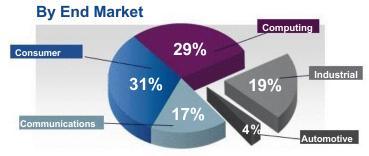
Revenue Growth





Revenue Profile – 1Q2013







First Quarter 2013 Financial Performance

In millions, except per share	1Q12	4Q12	1Q13	Q/Q	Y/Y
Revenue	\$144.7	\$163.3	\$177.0	\$13.7	\$32.2
Revenue Growth				8.4%	22.3%
Gross Margin % (GAAP)	23.3%	26.5%	26.1%	-40bp	280bp
Gross Margin % (non-GAAP)	23.3%	26.5%	27.1%	60bp	380bp
Operating Profit (GAAP)	\$33.7	\$43.2	\$46.2	\$3.0	\$12.5
Net Income (GAAP)	\$4.9	\$4.1	-\$1.9	-\$6.0	-\$6.8
Net Income (non-GAAP)	\$4.1	\$6.2	\$7.5	\$1.3	\$3.4
EPS (GAAP)	\$0.10	\$0.09	-\$0.04	-\$0.13	-\$0.14
EPS (non-GAAP)	\$0.09	\$0.13	\$0.16	\$0.03	\$0.07
Cash Flow from Operations	\$13.4	\$16.4	\$31.3	\$14.9	\$17.9
EBITDA (non-GAAP)	\$21.2	\$24.1	\$23.1	-\$1.0	\$1.9



Balance Sheet

In millions	Dec 31, 2011 (adjusted)	Dec 31, 2012	Mar 31, 2013
Cash	\$130	\$157	\$200
Inventory	\$140	\$153	\$182
Current Assets	\$427	\$491	\$612
Total Assets	\$793	\$920	\$1145
Other Long-term Debt	\$ 3	\$ 44	\$ 214
Total Liabilities	\$144	\$200	\$432
Total Equity	\$649	\$720	\$712



2Q 2013 Business Outlook

A summery of the guidance for GAAP and non-GAAP financial measures as follows :

	GAAP	Non-GAAP
Revenue \$(millions)	\$206 to \$218	\$206 to \$218
Sequential growth (%)	16% to 23%	16% to 23%
Gross Margin (% of Revenue)	25.0% to 29.0%	27.0% to 31.0%
Operating Expense (% of Revenue)	22.6% to 24.6%	20.3% to 22.3%
Tax Rate (%)	14% to 20%	14% to 20%
Shares (million)	47.4	47.4



Strategy: Profitable Growth





A Winning Combination

A Strong Global Partnership



2012 Revenue 2012 Gross Margin \$634m* 25.1%

- High volume Discrete,
 Analog and Logic products
- Cost efficient packaging capabilities
- Strong global presence
- Broad product and customer base
- Consumer, computing and industrial focus



2012 Revenue 2012 Gross Margin \$142m* 27.5%

- Solid Standard Linear and Power Management offering
- Strong AC/DC Solutions for Switch-Mode Power Supply chargers and adaptors
- Cost effective China wafer fab capability and capacity
- Extensive China-based development team
- Strong China-local market position.

SYNERGIES

- Expanded application platform and broader Analog footprint
- Manufacturing synergies
- Operating synergies
- End equipment diversification
- Expanded customer base and distribution channels
- Expanded Asian position

* 2012 Pro Forma Financials = 3Q 2012 YTD plus mid-point of 4Q 2012 guidance



BCD Fits Diodes' M&A Strategy

MUST HAVE's	Degree of FIT
Synergistic with Diodes' packaging capabilities and capacity	1
Accretive in 1 year	1
PLUS FACTORS	
Enter new product area	1
Increase existing product portfolio	1
Gain access to process and/or packaging technology	2
Strengthen regional sales potential	1

1=Very synergistic, 2=Synergistic, 3=Fairly Synergistic



Diodes Strategy: Profitable Growth



BCD is another key milestone











Diodes was named one of the 10 Best Stocks of the Past 20 Years – March 2012

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